Characteristics STTH806

### 1 Characteristics

Table 2. Thermal parameters

Symbol	Parameter		Value	Unit
R <sub>th(j-c)</sub>	Junction to case	TO-220AC, D <sup>2</sup> PAK	2.5	° C/W
		TO-220AC Ins	4	C/VV

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25° C	V <sub>R</sub> = V <sub>RRM</sub>			8	μA
IR. A Heverse leakage of	Treverse leakage current	T <sub>j</sub> = 150° C	VR - VRRM		20	200	μΛ
V <sub>F</sub> <sup>(2)</sup> Forward volta	Forward voltage drop	T <sub>j</sub> = 25° C	I <sub>F</sub> = 8 A			1.85	V
	1 of ward voitage drop	T <sub>j</sub> = 150° C			1.10	1.40	

- 1. Pulse test:  $t_p = 5$  ms,  $\delta < 2$  %
- 2. Pulse test:  $t_p$  = 380  $\mu$ s,  $\delta$  < 2 %

To evaluate the conduction losses use the following equation:

 $P = 1.07 \times I_{F(AV)} + 0.041 I_{F^{2}(RMS)}$ 

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Тур	Max.	Unit
	Reverse recovery time	$I_F = 0.5 \text{ A}, I_{rr} = 0.25 \text{ A}, I_R = 1 \text{ A},$ $T_j = 25^{\circ} \text{ C}$			35	ns
t <sub>rr</sub>	Theverse recovery time	$I_F = 1 \text{ A, } dI_F/dt = -50 \text{ A/}\mu\text{s,}$ $V_R = 30 \text{ V, } T_j = 25^{\circ} \text{ C}$		40	55	10
I <sub>RM</sub>	Reverse recovery current	$I_F = 8 \text{ A}, dI_F/dt = -100 \text{ A/}\mu\text{s},$ $V_R = 400 \text{ V}, T_j = 25^{\circ} \text{ C}$		4.5	6.5	
t <sub>fr</sub>	Forward recovery time	$I_F = 8 \text{ A}$ $dI_F/dt = 100 \text{ A/µs}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25^{\circ} \text{ C}$			200	ns
V <sub>FP</sub>	Forward recovery voltage	$I_F = 8 \text{ A}$ $dI_F/dt = 100 \text{ A/µs}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}, T_j = 25^{\circ} \text{ C}$		3.5		V

STTH806 Characteristics

Figure 1. Conduction losses versus average current

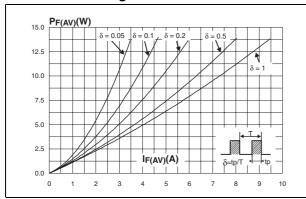


Figure 2. Forward voltage drop versus forward current

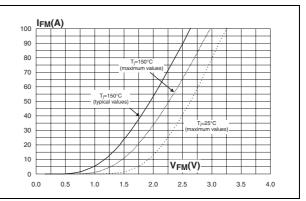
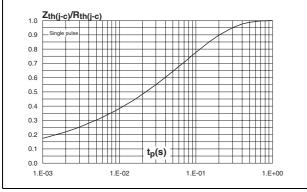


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

of thermal on to case versus

Figure 4. Peak reverse recovery current versus dl<sub>F</sub>/dt (typical values)



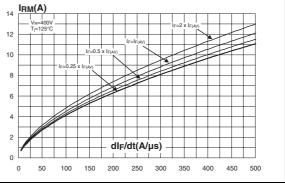


Figure 5. Reverse recovery time versus dl<sub>F</sub>/dt (typical values)

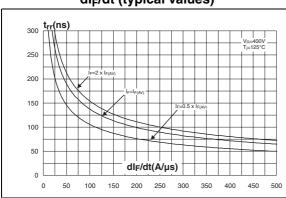
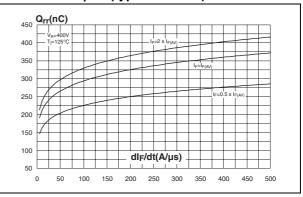


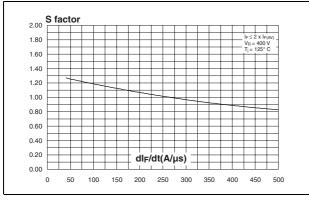
Figure 6. Reverse recovery charges versus dl<sub>F</sub>/dt (typical values)



Characteristics STTH806

Figure 7. Softness factor versus dl<sub>F</sub>/dt (typical values)

Figure 8. Relative variations of dynamic parameters versus junction temperature



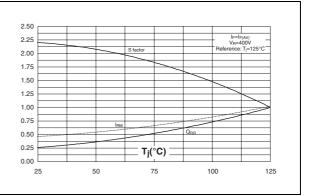
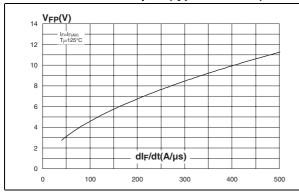


Figure 9. Transient peak forward voltage versus dl<sub>F</sub>/dt (typical values)

Figure 10. Forward recovery time versus dl<sub>F</sub>/dt (typical values)



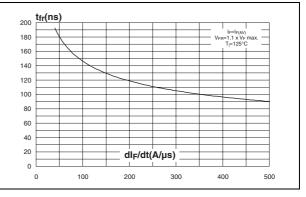
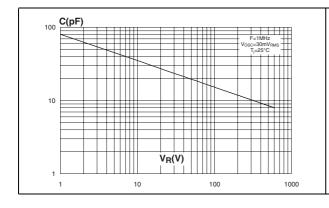
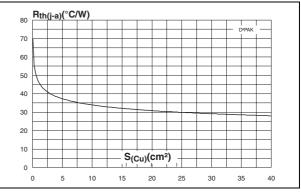


Figure 11. Junction capacitance versus reverse voltage applied (typical values)

Figure 12. Thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4,  $e_{CU}$  = 35  $\mu$ m)





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Inches

Max.

0.181

0.106

0.009

0.037

0.067

0.024

0.054

0.368

0.409

0.208

0.624

0.055

0.069

0.126

Min.

0.173

0.098

0.001

0.027

0.045

0.017

0.048

0.352

0.393

0.192

0.590

0.050

0.055

0.094

0.016 typ.

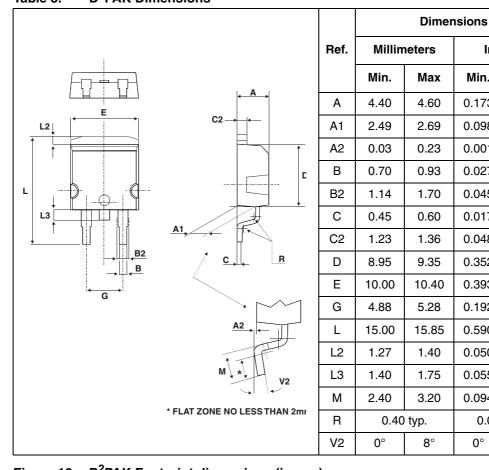
#### Package mechanical data 2

Epoxy meets UL94, V0

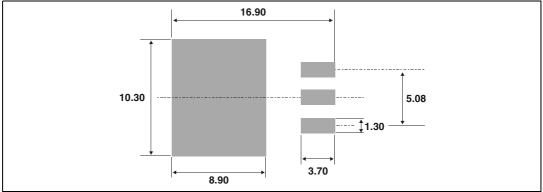
Cooling method: by conduction (C) Recommended torque value: 0.80 Nm

Maximum torque value: 1.0 Nm

D<sup>2</sup>PAK Dimensions Table 5.

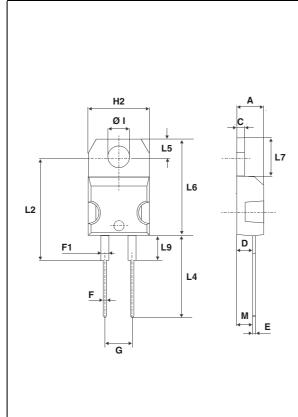






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Table 6. TO-220AC Dimensions



	Dimensions				
Ref.	Millim	neters	Inches		
	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.173	0.181	
С	1.23	1.32	0.048	0.051	
D	2.40	2.72	0.094	0.107	
Е	0.49	0.70	0.019	0.027	
F	0.61	0.88	0.024	0.034	
F1	1.14	1.70	0.044	0.066	
G	4.95	5.15	0.194	0.202	
H2	10.00	10.40	0.393	0.409	
L2	16.40	O typ.	0.645 typ.		
L4	13.00	14.00	0.511	0.551	
L5	2.65	2.95	0.104	0.116	
L6	15.25	15.75	0.600	0.620	
L7	6.20	6.60	0.244	0.259	
L9	3.50	3.93	0.137	0.154	
М	2.6 typ.		0.102 typ.		
Diam. I	3.75	3.85	0.147	0.151	

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**Dimensions** Ref. Millimeters Inches Min. Тур. Max. Min. Typ. Max. 15.20 15.90 0.598 0.625 Α 3.75 0.147 a1 a2 13.00 14.00 0.511 0.551 Ø١ В 10.00 10.40 0.393 0.409 0.034 b1 0.61 0.88 0.024 b2 1.23 1.32 0.048 0.051 С 4.40 4.60 0.173 0.181 c2 0.49 0.70 0.019 0.027 с1 2.40 0.094 0.107 c2 2.72 4.80 5.40 0.189 0.212 е F 6.20 0.244 0.259 6.60 с1 ØI 3.75 3.85 0.147 0.151 14 15.80 16.40 16.80 0.622 0.646 0.661 L 2.65 2.95 0.104 0.116 12 1.14 0.044 1.70 0.066 М 2.60 0.102

Table 7. TO-220AC Ins Dimensions

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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Ordering information STTH806

# 3 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH806G	STTH806G	D <sup>2</sup> PAK	1.48 g	50	Tube
STTH806G-TR	STTH806G	D <sup>2</sup> PAK	1.48 g	1000	Tape and reel
STTH806D	STTH806D	TO-220AC	1.90 g	50	Tube
STTH806DIRG	STTH806DI	TO-220AC Ins	2.30 g	50	Tube

## 4 Revision history

Date	Revision	Description of Changes
18-May-2006	1	First issue.
10-Aug-2006	2	Changed part number STTH806DI to STTH806DIRG.

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